

# WS4A010065F

## Silicon Carbide Schottky Diode

V <sub>RRM</sub>	=	650	V
$I_F(T_C \leq 130^{\circ}C)$	=	10	A
$\mathbf{Q}_{\mathrm{C}}$	=	25	nC

## **Features**

- New Thin Wafer Technology
- Low Forward Voltage Drop (V<sub>F</sub>)
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Positive Temperature Coefficient on V<sub>F</sub>
- Temperature-independent Switching

#### **Benefits**

- Replace Bipolar with Unipolar Device
- Reduction of Heat Sink Size
- Parallel Devices Without Thermal Runaway
- Essentially No Switching Losses

## **Applications**

- Switch Mode Power Supplies
- Uninterruptible Power Supplies
- Motor drive, PV Inverter, Wind Power Station

## **Package**



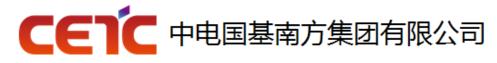
TO-220F-2



Part Number	Package	Marking
WS4A010065F	TO-220F-2	WS4A010065F

## **Maximum Ratings**

Symbol	Parameter	Value	Unit	Test Conditions	Note
$V_{RRM}$	Repetitive Peak Reverse Voltage	650	٧	T <sub>c</sub> = 25℃	
V <sub>RSM</sub>	Surge Peak Reverse Voltage	650	٧	T <sub>c</sub> = 25℃	
V <sub>R</sub>	DC Blocking Voltage	650	٧	T <sub>c</sub> = 25℃	
I <sub>F</sub>	Forward Current	10 9	Α	T <sub>C</sub> ≤ 130°C T <sub>C</sub> ≤ 135°C	
I <sub>FSM</sub>	Non-Repetitive Forward Surge Current	80	Α	$T_c = 25^{\circ}C$ , $t_p = 8.3$ ms, Half Sine Wave	
P <sub>tot</sub>	Power Dissipation	46.8	W	T <sub>c</sub> = 25℃	Fig.3
T <sub>J</sub> , T <sub>STG</sub>	Operating Junction and Storage Temperature	-55 to 175	$^{\circ}$		



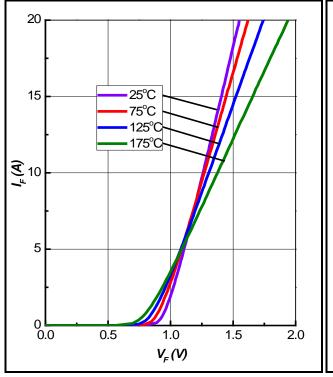
### **Electrical Characteristics**

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note	
V <sub>F</sub>	Forward Voltage	1.27	1.5	.,	I <sub>F</sub> = 10A, T <sub>J</sub> = 25°C	Fig 1	
		1.38	1.6 V	I <sub>F</sub> = 10A, T <sub>J</sub> = 175℃	Fig.1		
	D	6	50		$V_R = 650V, T_J = 25^{\circ}C$	F:- 2	
I <sub>R</sub>	Reverse Current	25	200	μΑ	$V_R = 650V, T_J = 175^{\circ}C$	Fig.2	
		640			$V_R = 0.1V, T_J = 25^{\circ}C, f = 1MHz$		
С	Total Capacitance	66	/	рF	$V_R = 200V, T_J = 25^{\circ}C, f = 1MHz$	Fig.5	
		48			$V_R = 400V, T_J = 25^{\circ}C, f = 1MHz$		
	T. 10 ''' 0	2-	,		V <sub>R</sub> = 400V, I <sub>F</sub> = 10A	F: 4	
$Q_{c}$	Total Capacitive Charge	25	/	nC	di/dt = 200A/μs, T₁ = 25℃	Fig.4	

### **Thermal Characteristics**

Symbol	Parameter	Тур.	Unit	Note
$R_{\theta JC}$	Thermal Resistance from Junction to Case	3.2	℃/w	Fig.6
$R_{\theta JA}$	R <sub>0JA</sub> Thermal Resistance from Junction to Ambient		℃/w	
T <sub>sold</sub> Soldering Temperature		260	ပ	

## **Typical Performance**



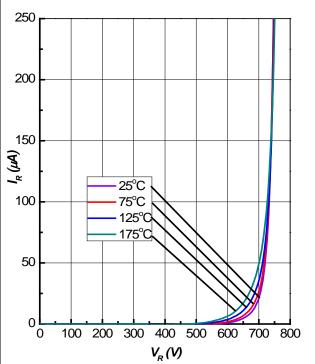
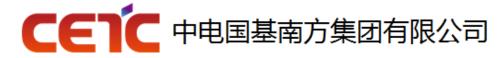
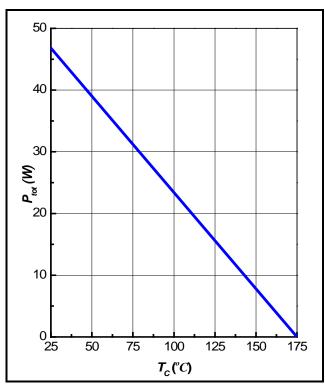


Figure 1. Forward Characteristics

**Figure 2. Reverse Characteristics** 



## **Typical Performance**



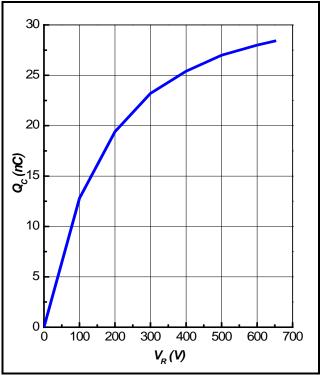
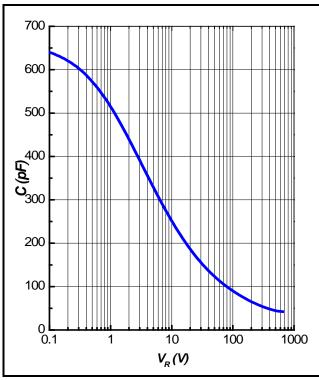


Figure 3. Power Derating

Figure 4. Total Capacitive Charge vs. Reverse Voltage



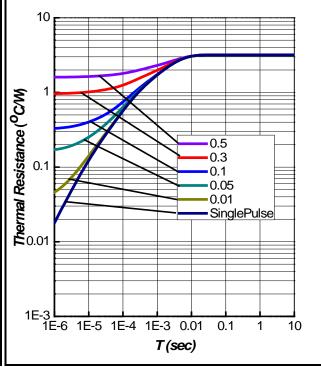
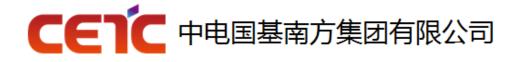


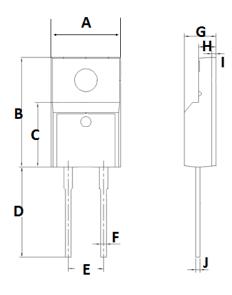
Figure 5. Total Capacitance vs. Reverse Voltage

**Figure 6. Transient Thermal Impedance** 



## **Package Dimensions**

Package TO-220F-2

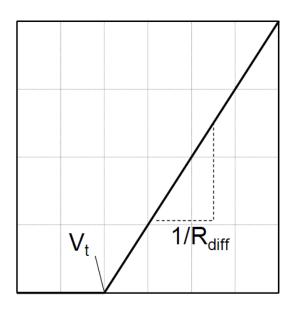




Symbol	Min. (mm)	Typ. (mm)	Max. (mm)
А	9.90	10.10	10.30
В	15.80	16.00	16.20
С	9.10	9.30	9.50
D	12.90	13.20	13.50
Е	4.70	5.00	5.30
F	0.60	0.80	1.00
G	4.55	4.75	4.95
Н	2.40	2.60	2.80
I	0.40	0.60	0.80
J	0.42	0.50	0.58

## **Simplified Diode Model**

#### **Equivalent IV Curve for Model**



### **Mathematical Equation**

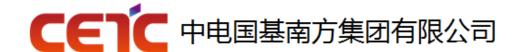
$$V_F = V_t + I_F \times R_{diff}$$

$$V_t = -0.001 \times T_j + 0.99 \text{ [V]}$$

$$R_{diff} = 6.9 \times 10^{-7} \times T_j^2 + 4.3 \times 10^{-5} \times T_j + 0.28 \text{ [}\Omega\text{]}$$

Note:

Tj = Diode Junction Temperature In Degrees Celsius, valid from 25°C to 175°C  $I_{F}$ = Forward Current Less than 20A



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